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Reply to Office Action dated February 22, 2006

AMENDMENTS TO THE CLAIMS

This listing of claims will replace all prior versions and listings of claims in the application.

Listing of Claims:

Claim 1 (Currently Amended): A liquid crystal display device, comprising:

a plurality of data lines arranged along a first direction on a substrate;

a plurality of gate lines arranged along a second direction perpendicular to the

first direction on the substrate to define a plurality of pixel regions, each of the gate lines having

at least one first set of protrusions and depressions extending in a direction substantially

perpendicular to a surface of the substrate on which the gate lines are arranged;

a driving device within each of the pixel regions;

a pixel electrode within each of the pixel regions; and

a metal layer overlapping each of the gate lines to create a storage capacitor, the

metal layer having at least one set of protrusions and depressions extending in a direction

substantially perpendicular to a surface of the substrate on which the metal layer is arranged.

Claim 2 (Original): The device according to claim 1, wherein the first set of protrusions

and depressions is arranged along the second direction of the gate lines.

Claim 3 (Original): The device according to claim 2, wherein the first set of protrusions

and depressions are arranged along the first direction of the data lines.

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Claim 4 (Original): The device according to claim 2, wherein the first set of protrusions

and depressions are arranged having a lattice shape.

Claim 5 (Original): The device according to claim 1, wherein the driving device includes

a thin film transistor.

Claim 6 (Original): The device according to claim 5, wherein the thin film transistor

includes:

a gate electrode on the substrate;

a gate insulating layer over the substrate;

a semiconductor layer on the gate insulating layer; and

a source electrode and a drain electrode on the semiconductor layer.

Claim 7 (Original): The device according to claim 6, further comprising at least one first

protrusion/depression layer on the substrate to form the first set of protrusions and depressions.

Claim 8 (Original): The device according to claim 7, wherein the first

protrusion/depression layer includes metal material.

Claim 9 (Original): The device according to claim 7, wherein the first

protrusion/depression layer includes insulation material.

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Claim 10 (Original): The device according to claim 6, further comprising at least one first groove formed within a surface of the substrate to form the first set of protrusions and depressions.

Claim 11 (Original): The device according to claim 6, wherein the metal layer is disposed on the gate insulating layer.

Claim 12 (Original): The device according to claim 11, wherein the metal layer includes metal material similar to metal material of the source electrode and the drain electrode.

Claim 13 (Original): The device according to claim 6, further comprising a second set of protrusions and depressions in the semiconductor layer.

Claim 14 (Original): The device according to claim 13, wherein the second set of protrusions and depressions is formed along the source electrode and the drain electrode.

Claim 15 (Original): The device according to claim 13, wherein the second set of protrusions and depressions is arranged in a lattice shape.

Claim 16 (Original): The device according to claim 13, further comprising a second protrusion/depression layer in the substrate to form the second set of protrusions and depressions.

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Claim 17 (Original): The device according to claim 16, wherein the second

protrusion/depression layer includes insulation material.

Claim 18 (Original): The device according to claim 16, wherein the second

protrusion/depression layer includes metal material.

Claim 19 (Original): The device according to claim 13, further comprising a second

groove formed in a surface of the substrate to form the second set of protrusions and depressions.

Claim 20 (Withdrawn): A liquid crystal display device, comprising:

a plurality of data lines and gate lines arranged in a substrate to define a plurality

of pixel regions;

a thin film transistor within each pixel region and including a gate electrode on

the substrate, a gate insulating layer on the substrate, a semiconductor layer on the gate

insulating layer and having protrusions and depressions, a source electrode and a drain electrode

on the semiconductor layer;

a passivation layer on an entire surface of substrate; and

a pixel electrode on the passivation layer.

Claim 21 (Withdrawn): The device according to claim 20, further comprising at least one

protrusion/depression layer on the substrate to provide protrusions and depressions in the

semiconductor layer.

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Claim 22 (Withdrawn): The device according to claim 21, wherein the protrusion/depression layer includes insulation material.

Claim 23 (Withdrawn): The device according to claim 21, wherein the protrusion/depression layer includes metal material.

Claim 24 (Withdrawn): The device according to claim 21, wherein the protrusion/depression layer is arranged along a direction between the source electrode and the drain electrode.

Claim 25 (Withdrawn): The device according to claim 21, wherein the protrusion/depression layer is arranged having a lattice shape.

Claim 26 (Withdrawn): The device according to claim 20, further comprising at least one groove formed in a surface of the substrate to provide protrusions and depressions in the semiconductor layer.

Claim 27 (Withdrawn): The device according to claim 26, wherein the groove is formed along a direction between the source electrode and the drain electrode.

Claim 28 (Withdrawn): The device according to claim 26, wherein the groove is arranged having a lattice shape.

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Claim 29 (Withdrawn): The device according to claim 20, further comprising a metal

layer arranged along a direction of the gate line to form a storage capacitor.

Claim 30 (Withdrawn): The device according to claim 29, further comprising a

protrusion/depression layer arranged along a direction of the gate line.

Claim 31 (Withdrawn): The device according to claim 29, further comprising a groove

formed along a direction of the gate line.

Claim 32 (Currently Amended): A method of fabricating a liquid crystal display device,

comprising:

forming a plurality of data lines arranged along a first direction on a substrate;

forming a plurality of gate lines arranged along a second direction perpendicular

to the first direction on the substrate to define a plurality of pixel regions, each of the gate lines

having at least one first set of protrusions and depressions extending in a direction substantially

perpendicular to a surface of the substrate on which the gate lines are arranged;

forming a driving device within each of the pixel regions;

forming a pixel electrode within each of the pixel regions; and

forming a metal layer overlapping each of the gate lines to create a storage

capacitor, the metal layer having at least one set of protrusions and depressions extending in a

direction substantially perpendicular to a surface of the substrate on which the metal layer is

arranged.

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Claim 33 (Original): The method according to claim 32, wherein the first set of

protrusions and depressions is arranged along the second direction of the gate lines.

Claim 34 (Original): The method according to claim 33, wherein the first set of

protrusions and depressions are arranged along the first direction of the data lines.

Claim 35 (Original): The method according to claim 33, wherein the first set of

protrusions and depressions are arranged having a lattice shape.

Claim 36 (Original): The method according to claim 32, wherein the driving device

includes a thin film transistor.

Claim 37 (Original): The method according to claim 36, wherein the thin film transistor

includes:

a gate electrode on the substrate;

a gate insulating layer over the substrate;

a semiconductor layer on the gate insulating layer; and

a source electrode and a drain electrode on the semiconductor layer.

Claim 38 (Original): The method according to claim 37, further comprising forming at

least one first protrusion/depression layer on the substrate to form the first set of protrusions and

depressions.

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Claim 39 (Original): The method according to claim 38, wherein the first

protrusion/depression layer includes metal material.

Claim 40 (Original): The method according to claim 38, wherein the first

protrusion/depression layer includes insulation material.

Claim 41 (Original): The method according to claim 37, further comprising forming at

least one first groove within a surface of the substrate to form the first set of protrusions and

depressions.

Claim 42 (Original): The method according to claim 37, wherein the metal layer is

disposed on the gate insulating layer.

Claim 43 (Original): The method according to claim 42, wherein the metal layer includes

metal material similar to metal material of the source electrode and the drain electrode.

Claim 44 (Original): The method according to claim 37, further comprising forming a

second set of protrusions and depressions in the semiconductor layer.

Claim 45 (Original): The method according to claim 44, wherein the second set of

protrusions and depressions is formed along the source electrode and the drain electrode.

Claim 46 (Original): The method according to claim 45, wherein the second set of

protrusions and depressions is arranged in a lattice shape.

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Claim 47 (Original): The method according to claim 44, further comprising forming a

second protrusion/depression layer in the substrate to form the second set of protrusions and

depressions.

Claim 48 (Original): The method according to claim 47, wherein the second

protrusion/depression layer includes insulation material.

Claim 49 (Original): The method according to claim 47, wherein the second

protrusion/depression layer includes metal material.

Claim 50 (Original): The method according to claim 44, further comprising forming a

second groove in a surface of the substrate to form the second set of protrusions and

depressions.

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